V?

	Application No.	Applicant(s)		
Notice of Allowability	10/809,659	YACH ET AL.	YACH ET AL.	
	Examiner	Art Unit		
	Thao X. Le	2814		
The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED or other appropriate coming GHTS. This application is	in this application. If not included nunication will be mailed in due course		
1. This communication is responsive to <u>07/26/05</u> .				
2. X The allowed claim(s) is/are 1-22.	•			
3. \boxtimes The drawings filed on <u>01 April 0325</u> are accepted by the Ex	kaminer.			
4. ☐ Acknowledgment is made of a claim for foreign priority una) ☐ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents have 2. ☐ Certified copies of the priority documents have 3. ☐ Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)). * Certified copies not received:	been received. been received in Applica cuments have been receiv	tion No ed in this national stage application fro		
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		le a reply complying with the requirem	nents	
5. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give			E OF	
6. CORRECTED DRAWINGS (as "replacement sheets") mus	t be submitted.			
(a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached				
1) hereto or 2) to Paper No./Mail Date (b) including changes required by the attached Examiner's		or in the Office action of		
Paper No./Mail Date				
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t	.84(c)) should be written or he header according to 37 (the drawings in the front (not the back) CFR 1.121(d).	of	
7. DEPOSIT OF and/or INFORMATION about the depo attached Examiner's comment regarding REQUIREMENT			ne	
Attachment(s) 1. ☑ Notice of References Cited (PTO-892)	5. Notice of	Informal Patent Application (PTO-152)	
2. Notice of Draftperson's Patent Drawing Review (PTO-948)		Summary (PTO-413), b./Mail Date		
3. Information Disclosure Statements (PTO-1449 or PTO/SB/C Paper No./Mail Date		's Amendment/Comment		
4. Examiner's Comment Regarding Requirement for Deposit		's Statement of Reasons for Allowanc	е	
of Biological Material	9. 🗌 Other			

Application/Control Number: 10/809,659 Page 2

Art Unit: 2814

EXAMINER'S AMENDMENT

1. This application is in condition for allowance except for the presence of claims 23 to 31 non-elected without traverse per amendment dated 30 June 2005 and telephone conversation with the applicant's Attorney on 25 July 2005. Accordingly, claims 23-31 been cancelled.

2. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with The Applicant's Attorney, Mr. Paul Katz, on 27 July 2005. The application has been amended as follows:

In the claim:

- Claim 1 line 19 after "plurality of first P+ diffusion" delete "; and a connection to the third N+ diffusion"
- Claim 22 line 25 after "plurality of first P+ diffusion" delete "; and a connection to the third N+ diffusion"
- 3. The following is an examiner's statement of reasons for allowance: claims 1-22 are allowed because the prior art of record neither anticipated nor rendered obvious all the limitations of the base claims 1 and 22 including a first lighter doped n-silicon well (first N-well), a first heavier doped n-silicon diffusion (first N+ diffusion), a second lighter

Art Unit: 2814

doped n-silicon well (second N-well); a second heavier doped n-silicon diffusion (second N+ diffusion) in the second N-well, a second heavier p-silicon diffusion (second P+ diffusion) in the second n-well, the second N+ diffusion is connected to the first N+ diffusion, a third heavier doped p-silicon diffusion (third P+ diffusion) in the P-well, the third P+ diffusion is connected to the second P+ diffusion; a bond pad connected to the plurality of first P+ diffusion.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thao X. Le whose telephone number is (571) 272-1708. The examiner can normally be reached on M-F from 8:00 AM - 4:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M. Fahmy can be reached on (571) 272 -1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Application/Control Number: 10/809,659

Art Unit: 2814

Page 4

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Thao X. Le 26 July 2005

> KONG PHAM PRIMARY EXAMINER